

HPGe X-ray detector performance at MIRION

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MIRION
TECHNOLOGIES

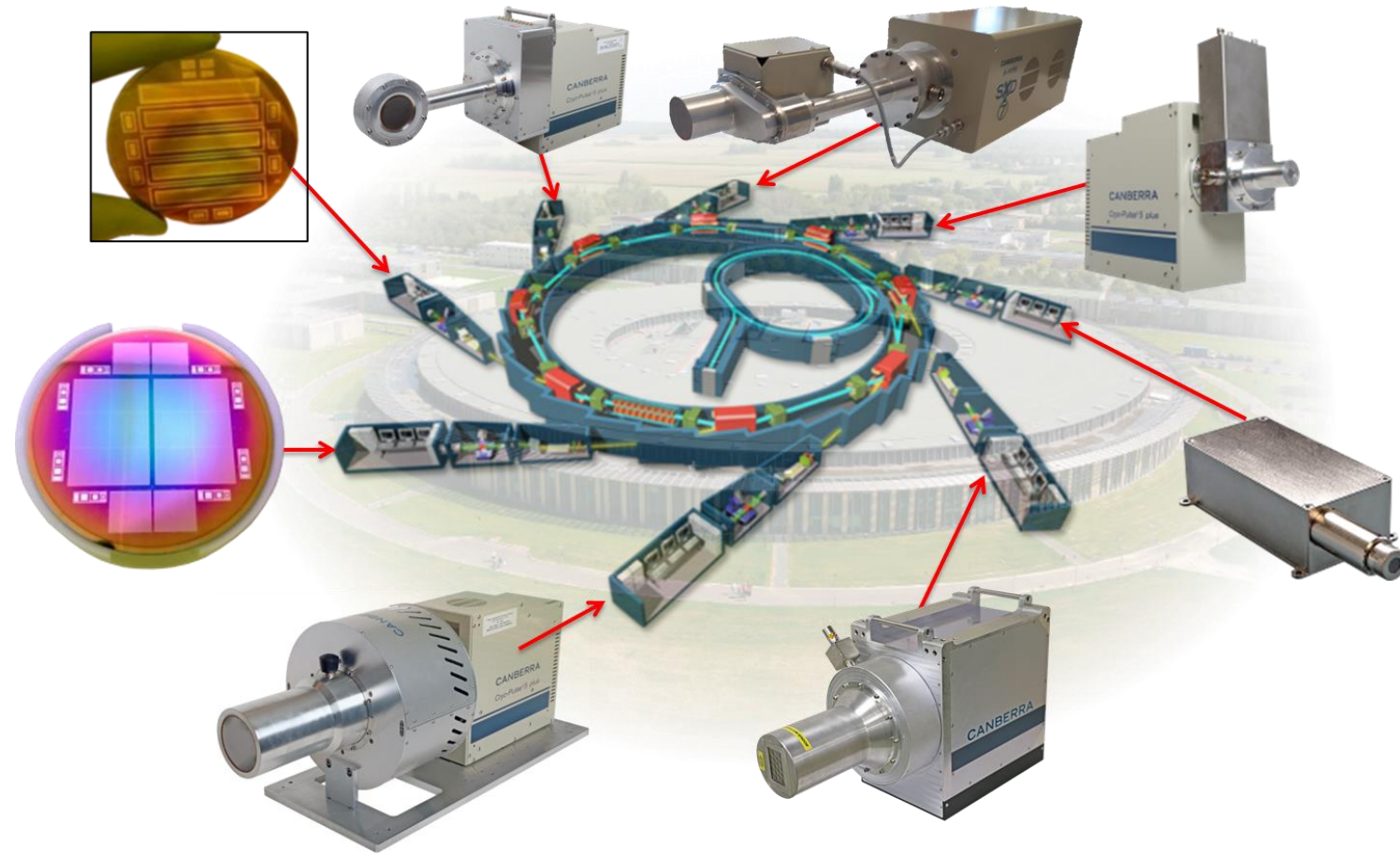
MIRION complete offer for Synchrotrons

- **Spectroscopy**

- Silicon: X-PIPS, SDD (Si drift diodes) – single or multichannel
- HPGe: single or multichannel

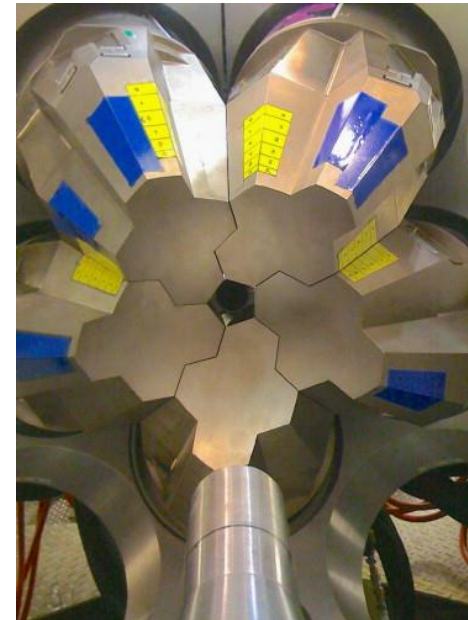
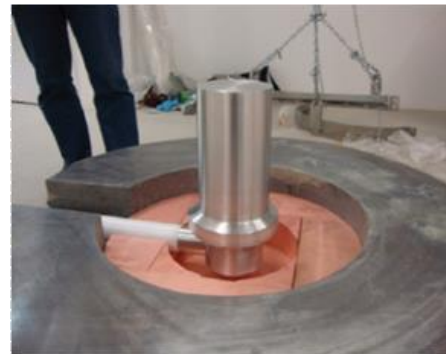
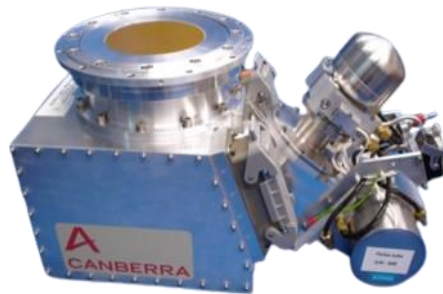
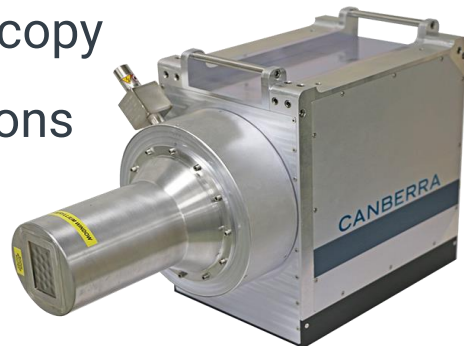
- **Imaging**

- Strip detectors: single side segmented detectors or double side segmented detectors (DSSD)
- Finely pixelated detectors, down to a micrometric pitch



MIRION Specialty HPGe detectors

- More than 50 years in expertise manufacturing HPGe detectors from standards to specialty solution
- Covering several fields of application
 - Fundamental nuclear research
 - Ultra-low contamination counting labs
 - **X-Ray Fluorescence**
 - OEM solutions
 - In-situ spectroscopy
 - Space applications

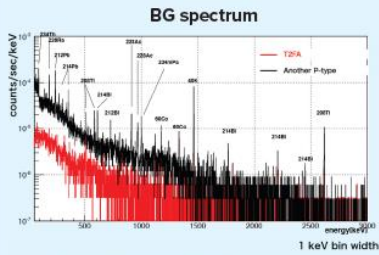


Ultra Low Background detectors

10⁻⁵ ct.s⁻¹.cm⁻¹
40-2700 keV range

DETECTOR PERFORMANCE

- Typical energy resolution
- Efficiency and well size configuration
- Background achieved with various detector in different underground lab around the world



Background spectra obtained for S-ULB coaxial detector [4]



EGMP 80-30 with double preamplifier (AC and DC) with ISOCS characterization



400CC P21 SAGeWell detector made with copper [4]

Material selection and screening of components to reduce mass and intrinsic background of critical components:

- Electronics components
- Soldering material
- Cable
- Screws

Metal selection: aluminum and/or copper with 0.1 ppb U-Th

Isocs characterization available

Electrically cooled detector

Specific configuration : double preamplifier

SPECIALTY ULTRA-LOW-BACKGROUND DETECTOR

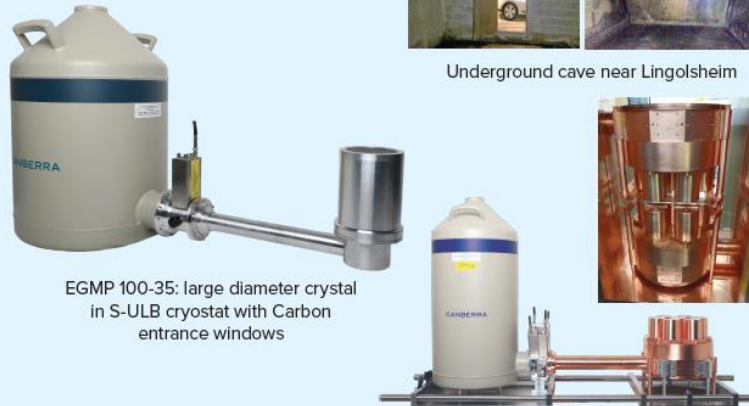
Cryostat design with various possibility:

- Arm length
- Detector head configuration
- Crystal size and diameter
- Multi germanium detector configuration
- Electrically segmented crystal

HPGe crystal selection to reduce cosmogenic activation with underground storage 700 mwe and no plane transportation



Underground cave near Lingolsheim



EGMP 100-35: large diameter crystal in S-ULB cryostat with Carbon entrance windows



Detector array[1] operated by CUP, IBS. Image copyright CUP, IBS, 2017.



SAGeWell detector installed inside a lead castle

SELECTION OF S-ULB DETECTOR PERFORMANCES

Detector	Crystal size (mm)	Weight (kg)	Location Lab	122 keV FMHM (keV)	1332 keV FWHM (keV)	Background 40 to 2700 keV (counts per kg per day)
EGMP 90- 30 BeGe detector	90 x 30	1,03	Boulby	0,63	1,73	150 [2]
EGMP 90-33 BeGe detector	90 x 33	1,13	SURF	0,61	1,75	X
EGMP 100-35	100 x 35	1,48	CANADA	0,66	1,72	X
P21 400CC Well detector	80 x 85	2,13	Canfranc	0,69	1,91	640 [5]
P21 400CC Well detector	80 x 85	2,13	Modane	0,74	1,87	505 [3]
P21 250 CC Well detector	80 x 63	1,33	HADES	0,68	1,88	795 [6]
EGPC 80-185 P-type Coaxial detector	75 x 73	1,68	KAMIOKA	0,85	1,9	115 [4]
EGPC 120-215 P-Type coaxial detector	84 x 84	2,44	CHINA	0,93	1,98	X

REFERENCES

- [1] D.S. Leonard et al. NIM A 989 (2021) 164954
- [2] Courtesy P.R. Scovell, STFC Boulby underground Laboratory
- [3] Courtesy P. Sabatier, University Savoie Mont Blanc
- [4] Courtesy K. Ichimura, Tohoku University
- [5] Courtesy G. Zuzel, Jagiellonian University
- [6] Courtesy M. HULT, JRC-Geel



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HPGe detectors for X-ray applications

TYPICAL VALUES

- HPGe detection material
 - Thickness: typical 5 to 15 mm
 - Energy range: from 2 up to 200 keV
 - High Voltage bias: up to 2 kV
 - ELEMENTS: Typical 50mm^2 – 450mm^2 up to 1200mm^2
 - MONOLITHIC SEGMENTED: typical 64mm^2
- Cryogenic cooling required -185°C : CP5-Plus cryocooler
- Entrance window: Beryllium OR Aluminum for energies higher than $\sim 20\text{keV}$
- CMOS Electronics
 - Up to several million count per seconds
 - Dedicated readout electronics to sustain such high count-rates



Basic decision criteria HPGe vs. SDD

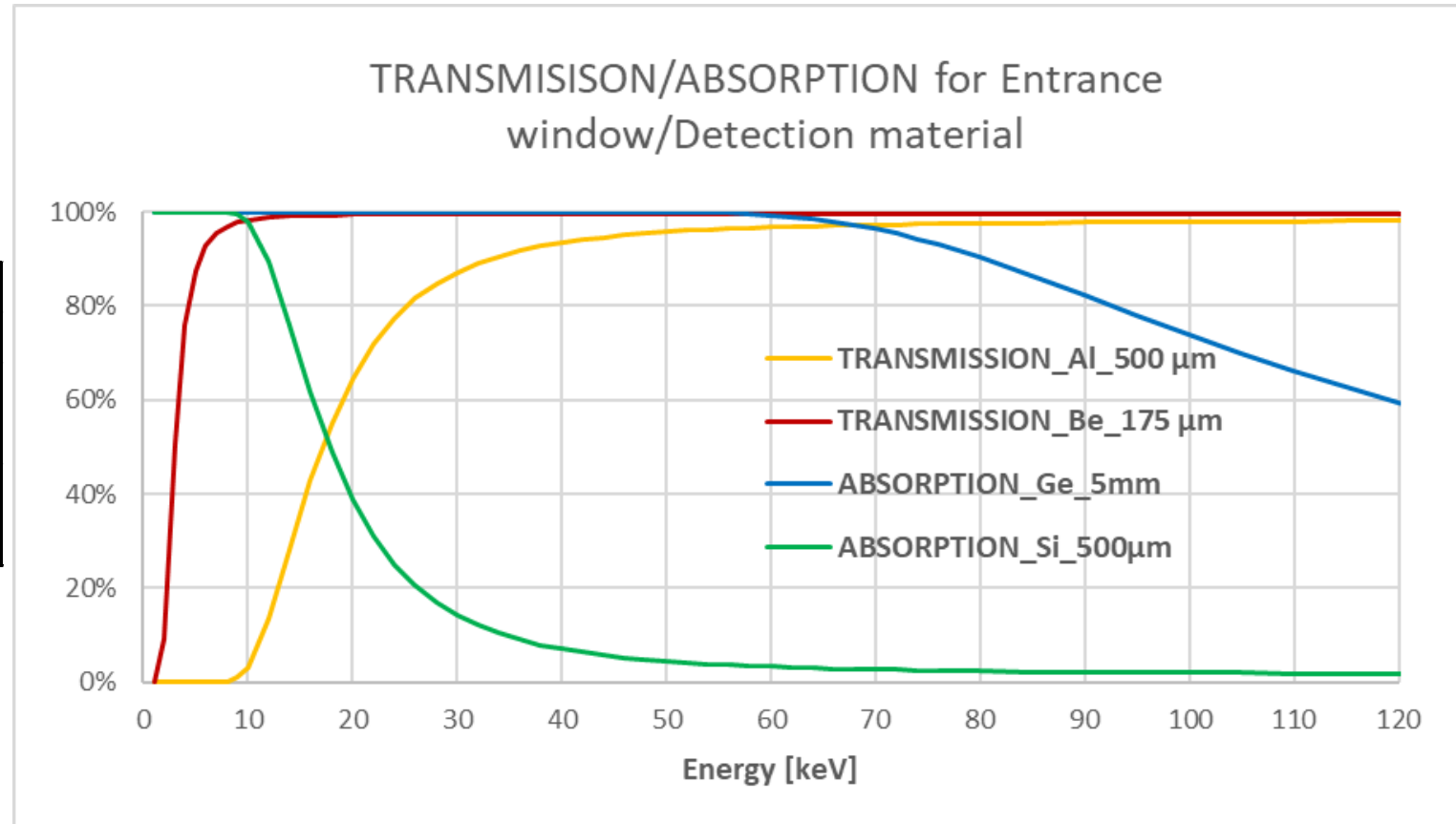
EFFICIENCY

- What is the energy range of the physics to be done ?

Energy range	Best efficiency
< 10 keV	SDD
10 - 20 keV	SDD HPGe with Beryllium entrance window
> 20 keV	HPGe with Aluminum entrance window HPGe with Beryllium entrance window ++

MITIGATION

- 11 keV X-ray emission line of Ge
- SDDs have superior Peak-to-Valley ratio for Fe55



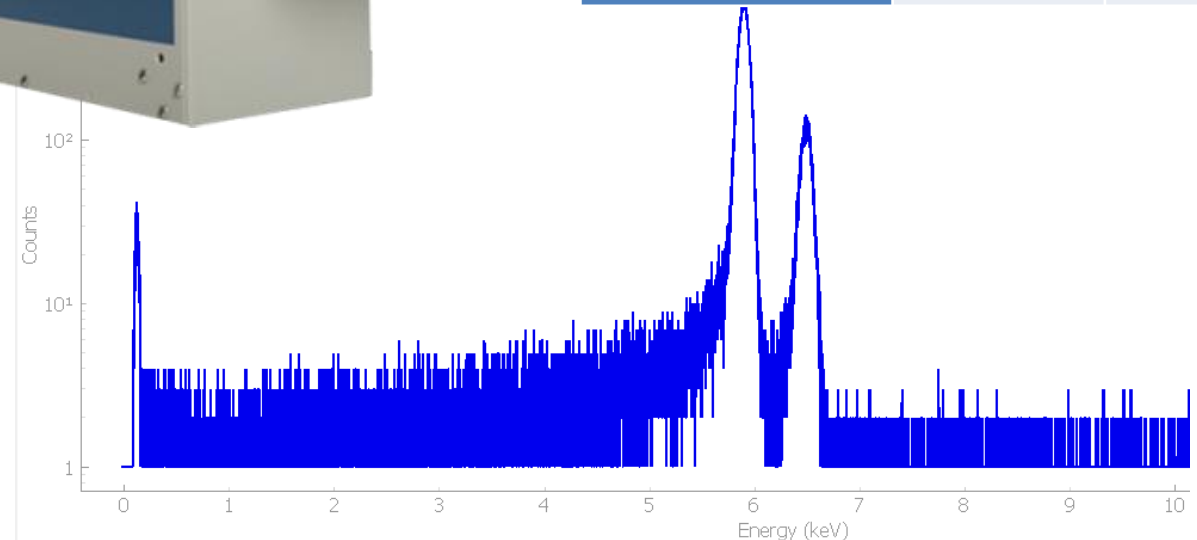
Single Element

- Single crystal / single channel detector
 - 50mm² (Ø 8mm) – 5mm thick
 - 200mm² (Ø 16mm) – 10 mm thick
 - 500mm² (Ø 25mm) – ≥ 10 mm thick
 - Larger version possible
- Low fluorescence Aluminum cryostat
- Optional
 - Be / Al / Windowless
 - CP5-plus electrical cooler
 - Water chiller
- Electronics fast CMOS preamplifiers

**Demo Detector
available**



Energy resolution	Typical	Guaranteed
1000 cps 6µs shaping time	< 120 eV	< 130 eV
100 000 cps 0.5 µs shaping time	< 120 eV	< 145 eV
100 000 cps 0.1 µs shaping time	< 150 eV	< 170 eV
1 000 000 cps FalconX or xpress3 mini	< 175 eV	< 190 eV

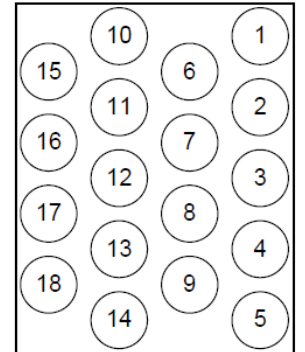


Multi-Element

- 18 element detector
- Active area for each element: 50mm² (8mm diam)
- Active thickness: 5mm
- Low fluorescence Aluminum cryostat
- Be window thickness 50μm
- CP5-plus electrical cooler
- Water chiller
- Ion pump
- Electronics fast CMOS preamplifiers



ELEMENT	FWHM at 5.9 keV in eV			
	3-6 μs / 1kcps (≤ 140 eV)	0.5 μs / 100kcps (≤ 160 eV)	0.1 μs / 100kcps (≤ 200 eV)	1Mcps (≤ 250 eV)
1	124	142	165	190
2	113	135	166	193
3	125	145	160	181
4	122	150	188	215
5	125	141	163	186
6	122	147	172	190
7	121	144	159	184
8	126	147	176	201
9	132	134	168	205
10	121	141	167	194
11	122	136	168	193
12	120	134	158	178
13	130	137	166	185
14	123	144	165	193
15	131	156	200	231
16	128	138	152	171
17	118	130	152	182
18	117	130	159	188



Monolithic Pixelated

- Total active area : 48mm x 48mm
- Active thickness: 7mm
- Segmentation: 36 pixels / 25 / 16



31	25	19	13	7	1
32	26	20	14	8	2
33	27	21	15	9	3
34	28	22	16	10	4
35	29	23	17	11	5
36	30	24	18	12	6

Detector front view

- Low fluorescence aluminum cryostat
- CP5-plus electrical cooler
- Be window thickness 175 μ m
- Collimator: Titanium alloy with 100 μ m Al coating
- Electronics fast CMOS preamplifiers

FWHM AT 5.9 KEV

PIXEL	1 KCPS < 160 EV	100 KCPS < 230 EV	PIXEL	1 KCPS < 160 EV	100 KCPS < 230 EV	PIXEL	1 KCPS < 160 EV	100 KCPS < 230 EV
1	154	189	13	146	175	25	151	184
2	147	192	14	142	176	26	143	188
3	146	178	15	145	185	27	147	188
4	150	176	16	150	188	28	154	209
5	153	187	17	157	202	29	157	198
6	155	187	18	154	204	30	150	206
7	148	186	19	150	186	31	145	182
8	158	195	20	153	186	32	157	173
9	147	187	21	158	185	33	150	185
10	150	187	22	148	185	34	52	189
11	158	212	23	160	204	35	145	192
12	148	195	24	152	207	36	151	206

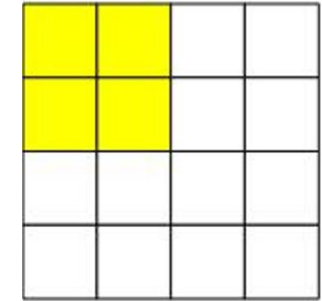


Pixel Next Generation

- Total active area : 36mm x 36mm
- Active thickness: 5 mm
- Segmentation:
 - Linear or squared arrangement
 - Pixels: 4x4 / 8x2 / 8x1 / 2x2
- Low fluorescence aluminum cryostat
- CP5-plus electrical cooler
- Electronics fast CMOS preamplifiers



4 channels equipped, 12 channels to be equipped later.



Channel	Energy resolution Vs (energy / count rate / Gaussian shaping time)			
	6keV 1kcps 4μs [eV]	6keV 100kcps 0.5μs [eV]	60keV 1kcps 4μs [eV]	122keV 1kcps 4μs [eV]
1	124	125	329	483
2	119	128	341	487
3	117	126	328	472
4	126	134	340	483

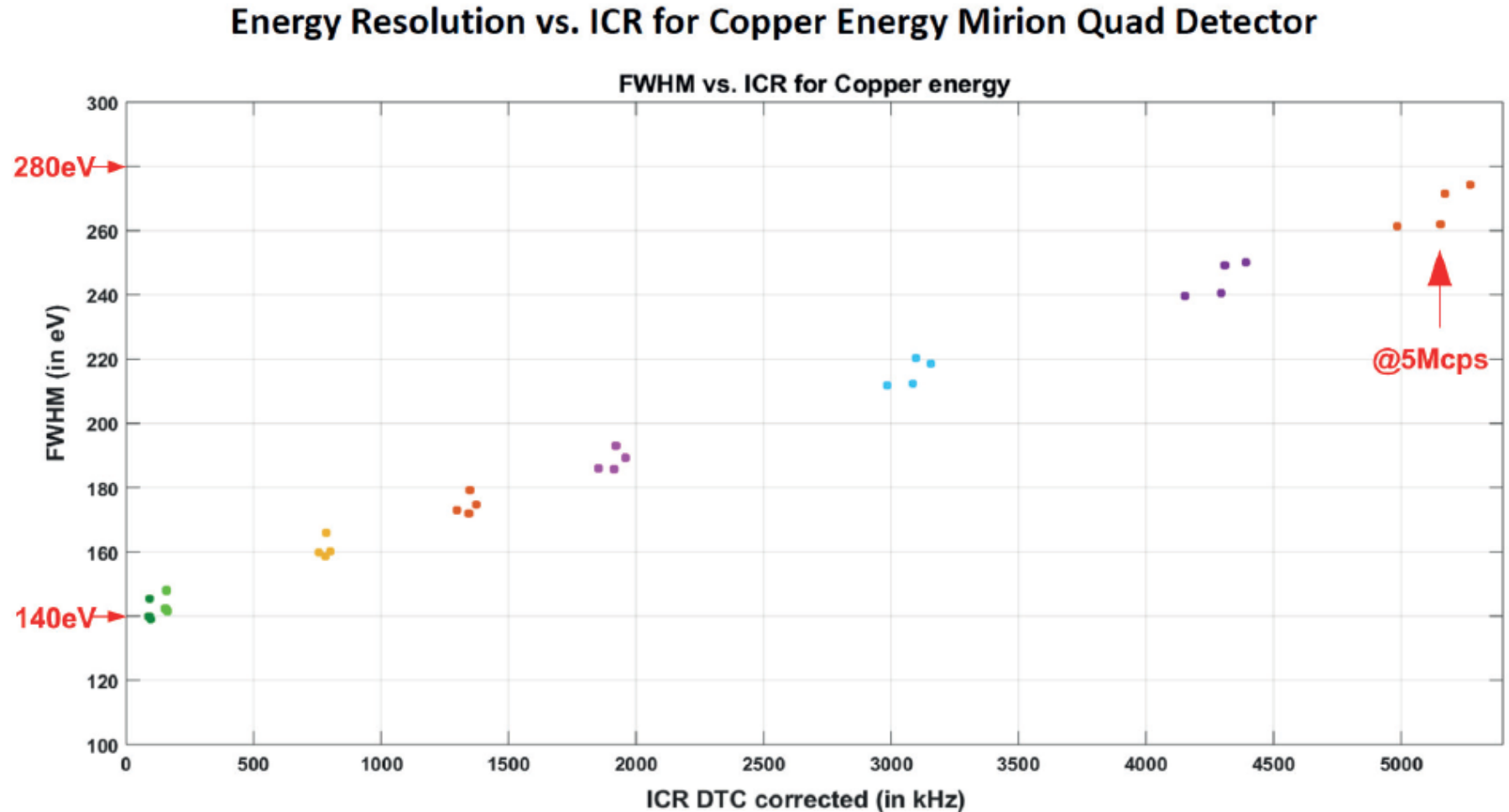
**Demo Detector
available**



Pixel Next Generation

- Copper Ka – 8.1 keV
- Measurement and tests performed at DLS
 - XPRESS4 readout

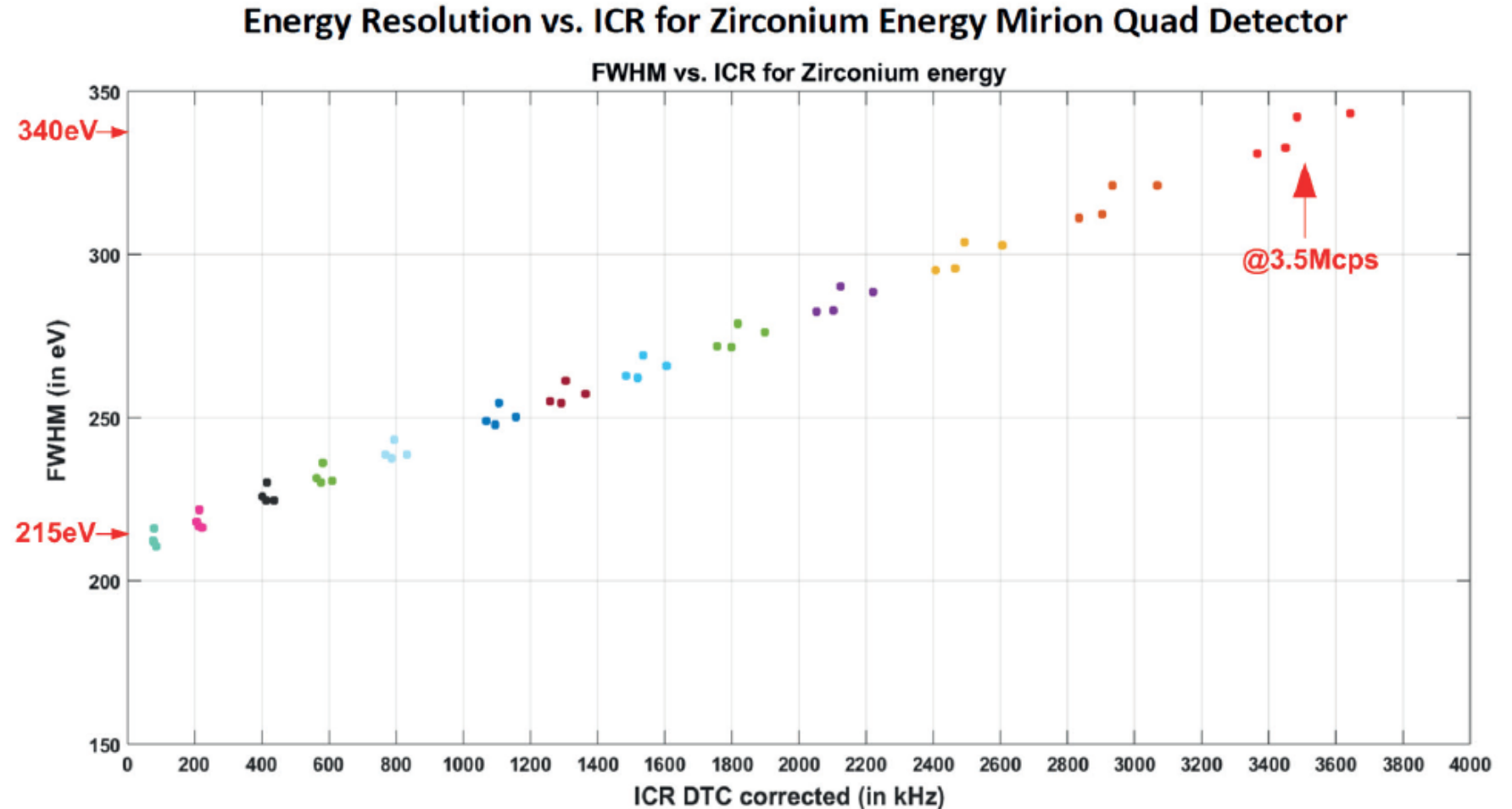
Figure by courtesy of Sudeep Chatterji & Nicola Tartoni, Diamond Light Source



Pixel Next Generation

- Zirconium Ka – **15.8 keV**
- Measurement and tests performed at DLS
 - XPRESS4 readout

Figure by courtesy of Sudeep Chatterji & Nicola Tartoni, Diamond Light Source



Monolithic Pixel vs. Multi-Elements detectors

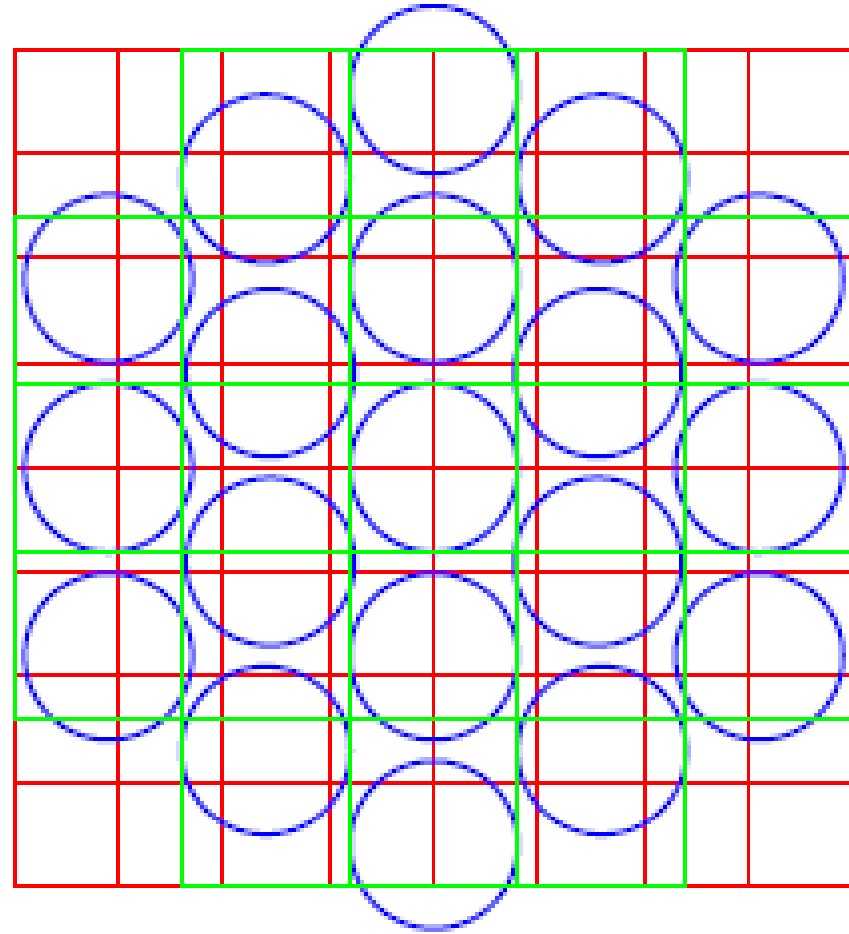
Detector parameter	Monolithic pixels detectors	New generation pixels detectors	Discrete arrays
Energy resolution	Good	Best	Best
Peak to background	Good	Best	Best
Count rate capability	Good	Best	Best
Number of channels	Up to 100	Up to 16	Up to 24
Solid angle	Largest	Very good	Large surface Lower active coverage
Energy range	2 : 200 keV	2 : 200 keV (down to 0.3 keV)	2 : 200 keV (down to 0.3 keV)
Charge sharing	Mitigated (collimator grid)	None	None



Monolithic Pixel vs. Multi-Elements detectors

Solid angle Coverage

- 19 elements array
- 64 pixel – monolithic
- New generation pixel detector



Custom configurations

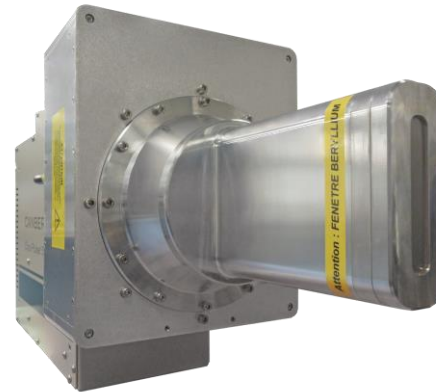
Idea ?
Hybrid 8-element
4x SDD
4x HPGe

Windowless cryostats

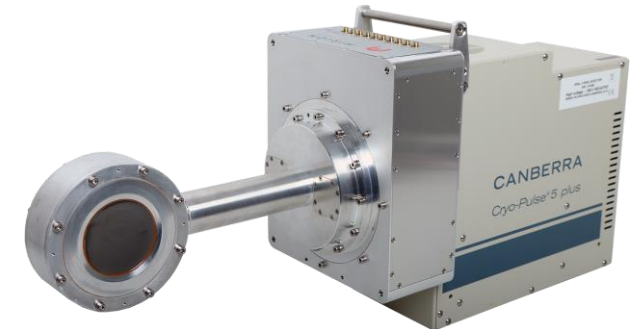
- Gate Valve to open the cryostat to vacuum chamber
- Linear stage and bellow to move the HPGe inside the chamber



Elements arrangement



7-element linear



4-pix NG transmission cryostat

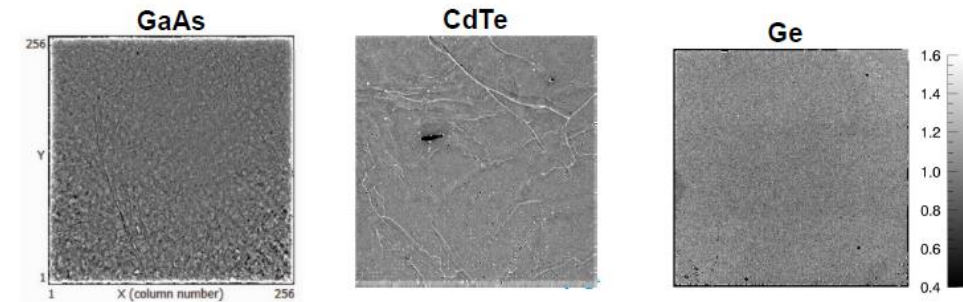
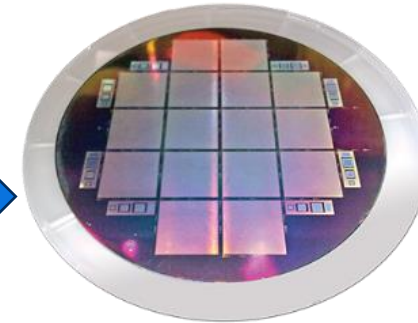
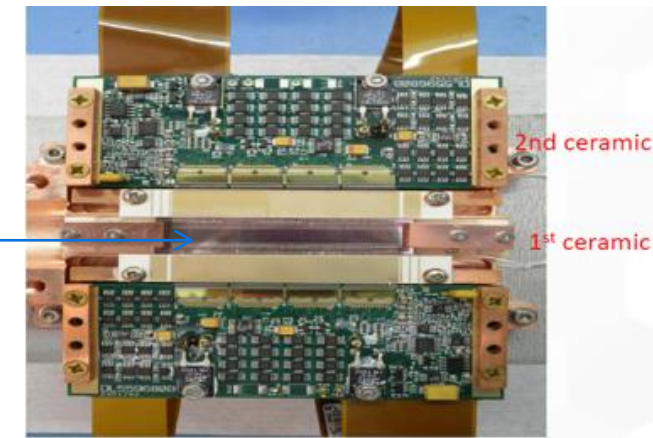
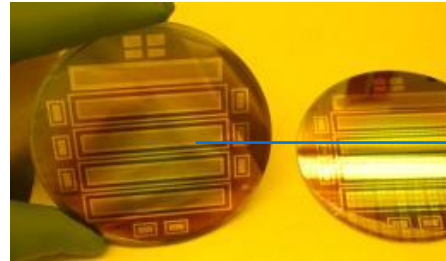


Wafers

Segmented HPGe wafers

Some realisations

- Linear diffractor – 1024 strip – 50 μm pitch – 1mm-thick
- Medipix chip – 256x256 pix, 50 μm pitch – 1 mm-thick
- LEAPS – 10 segments pattern – 4mm-thick

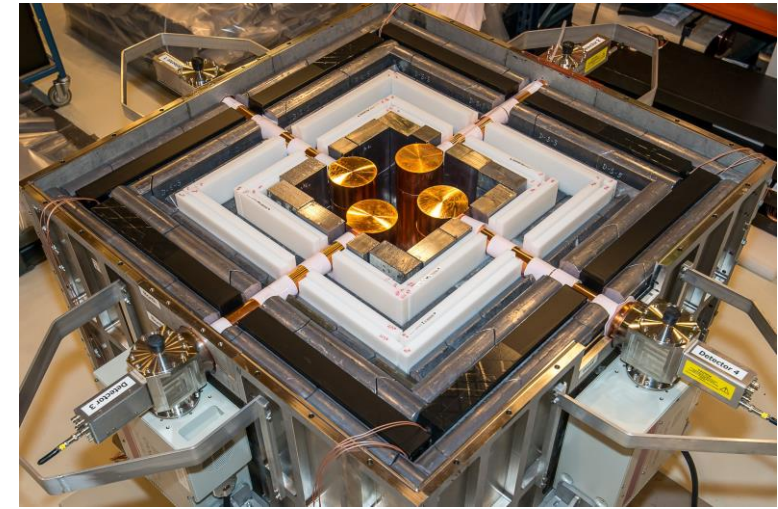


D Pennicard | LAMBDA, High-Z sensors and the HORUS simulation tool | Three-way meeting, APS, August 2013 | Page 28



Exotic detectors

<https://en.wikipedia.org/wiki/CONUS-Experiment#/>



Neutrino / Dark matter applications

High efficiency Point Contact detectors with best pulser resolution for Rare Events detection

- CMOS electronics for best low-energy threshold
- Large (2.4 kg) PPC detectors
- Radiopure: Ultra-Low background materials
- <80 eV FWHM test pulser with 2.4 kg crystal



Conclusion & outlook

CONCLUSION

- Specialty HPGe detector solutions
- Large panel of existing solutions
 - Single channel
 - Arrays
 - Wafers – fine pitch
- Configuration customization

OUTLOOK – improve performances

- Mid-term : new HPGe consolidation
 - Better performances FWHM & high count-rates
 - Check for reproducibility & robustness
- Long-term R&D:
 - Crystals for Holes charge collection with faster risetime and improved high-energy performances

